Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

1.120 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Mounting Method:

Threaded stud

Thread Size:

0.500 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

70.0 gate to source cutoff voltage

Current Rating Per Characteristic:

2.00 amperes source cutoff current major and 2.00 amperes source cutoff current megahertz

Power Rating Per Characteristic:

5.0 watts small-signal input power, common-collector blank

Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

Special Features:

Junction pattern arrangement: pnpn

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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